

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

MCH3414 General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	4	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)	0.8	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linis
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =0.5A	0.45	0.9		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =0.5A, V _G S=10V		480	630	mΩ
	RDS(on)2	ID=0.5A, VGS=4V		640	900	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		70		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		9.0		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		6.5		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		5		ns
Rise Time	t _r	See specified Test Circuit.		4		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		12		ns
Fall Time	tf	See specified Test Circuit.		12		ns

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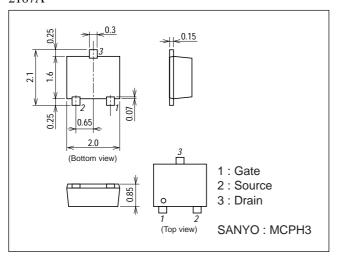
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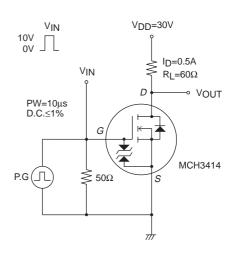
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =1A		3.0		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =1A		0.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =1A		0.6		nC
Diode Forward Voltage	VSD	IS=1A, VGS=0		0.9	1.2	V

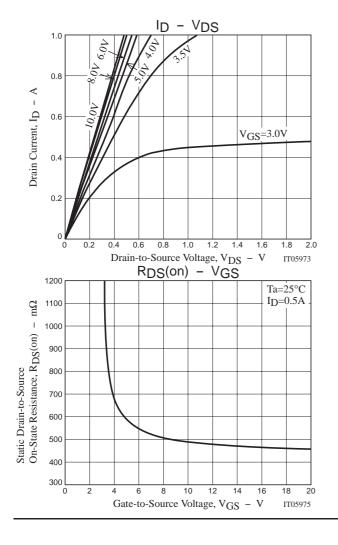
Package Dimensions

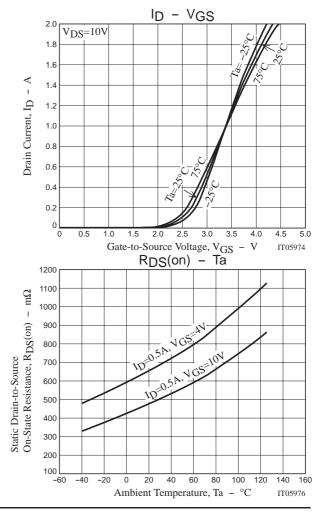
unit : mm 2167A

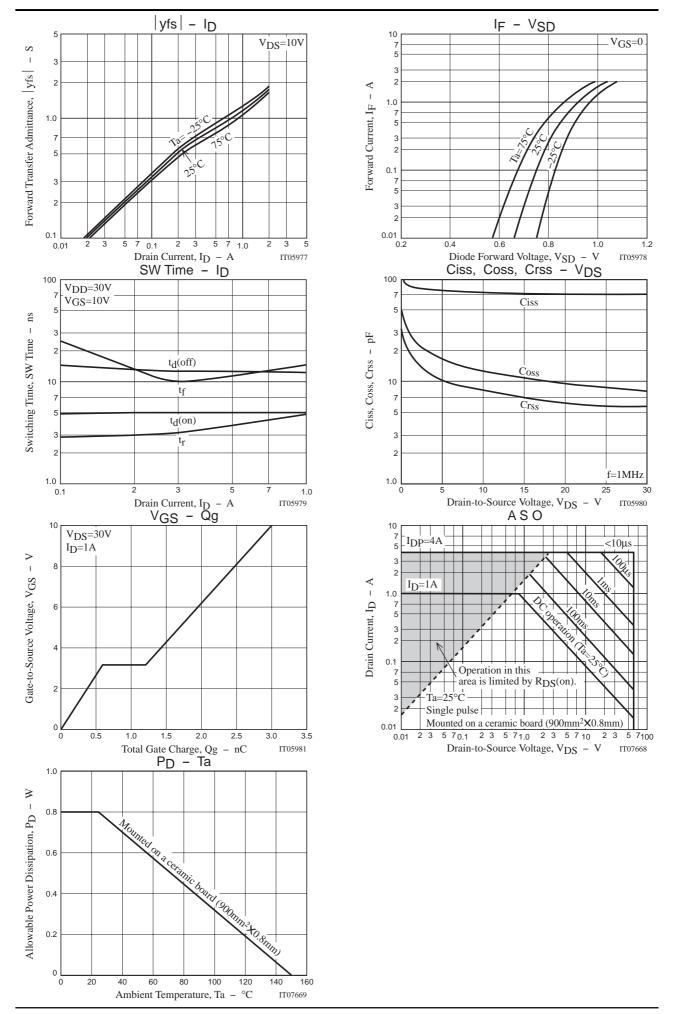


Switching Time Test Circuit









Note on usage: Since the MCH3414 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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